



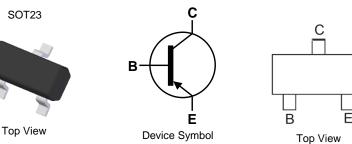
PNP SMALL SIGNAL TRANSISTOR IN SOT23

Features

- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (£3)
- Weight: 0.008 grams (Approximate)



Pin-Out

Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel	Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC856A-7-F	AEC-Q101	K3A	7	3,000	BC857B-7-F	AEC-Q101	K3B	7	3,000
BC856AQ-7-F	Automotive	K3A	7	3,000	BC857BQ-7-F	Automotive	K3B	7	3,000
BC856B-7-F	AEC-Q101	K3B	7	3,000	BC857B-13-F	AEC-Q101	K3B	13	10,000
BC856BQ-7-F	Automotive	K3B	7	3,000	BC857C-7-F	AEC-Q101	K3G	7	3,000
BC856B-13-F	AEC-Q101	K3B	13	10,000	BC857C-13-F	AEC-Q101	K3G	13	10,000
BC856BQ-13-F	Automotive	K3B	13	10,000	BC858A-7-F	AEC-Q101	K3A	7	3,000
BC857A-7-F	AEC-Q101	K3A	7	3,000	BC858B-7-F	AEC-Q101	K3B	7	3,000
					BC858C-7-F	AEC-Q101	K3G	7	3,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

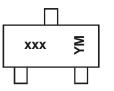
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.

5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code (Please see Ordering Information) YM = Date Code Marking Y or \overline{Y} = Year (ex: A = 2013)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key												
Year	2010	20	011	2012	2	2013	2014		2015	2016		2017
Code	Х		Y	Z	A		В		С	D		E
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Month	Uan	100	Intal		wiay	oun	oui					
Code	1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris	tic	Symbol	Value	Unit
	BC856		-80	
Collector-Base Voltage	BC857	V _{CBO}	-50	V
	BC858		-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	V _{CEO}	-45	V
	BC858		-30	
Emitter-Base Voltage		V _{EBO}	-5.0	V
Continuous Collector Current		lc	-100	mA
Peak Collector Current		I _{CM}	-200	mA
Peak Emitter Current		I _{EM}	-200	mA
Peak Base Current		I _{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 6)	P	310	mW
	(Note 7)	P _D	350	TTIVV
Thermal Desistance Junction to Ambient	(Note 6)		403	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	R _{0JA}	357	C/VV
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W
Operating and Storage Temperature Range	T _J ,T _{STG}	-65 to +150	°C	

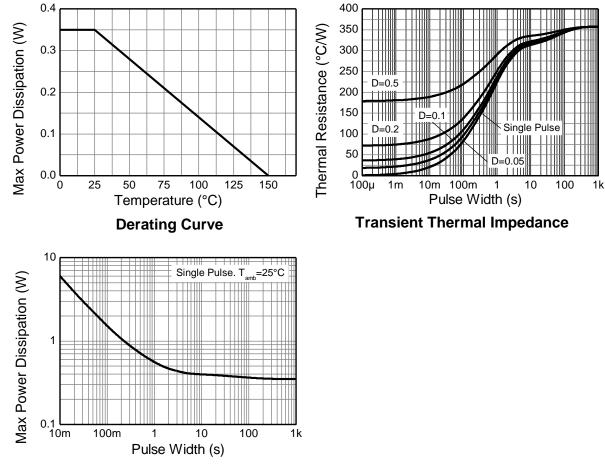
ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air Notes: For a device mounted on minimum recommended pad layout 102 copper that is conditions whilst operating in a steady-state.
Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.
Thermal resistance from junction to solder-point (at the end of the leads).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information



Pulse Power Dissipation



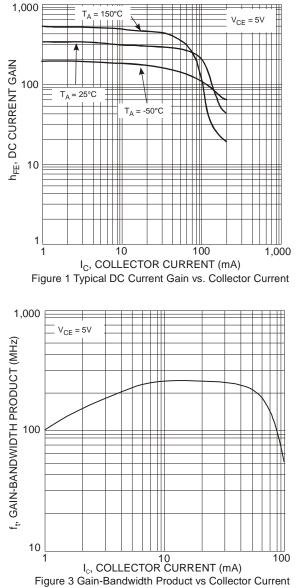
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

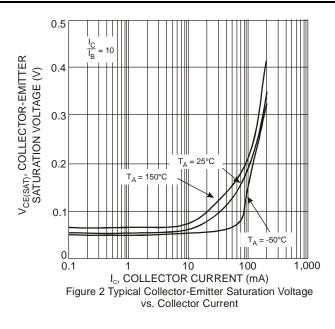
Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC856		-80					
Collector-Base Breakdown V	'oltage	BC857	BV CBO	-50	—	—	V	I _C = -10μA	
		BC858		-30					
Collector-Emitter Breakdown	Voltage	BC856	-65						
(Note 10)	vollage	BC857	BV _{CEO}	-45	—	—	V	$I_{\rm C} = -10 {\rm mA}$	
· · · ·		BC858		-30					
Emitter-Base Breakdown Vo	ltage		BVEBO	-5	—	_	V	$I_E = -1\mu A$	
Collector Cutoff Current			long	_	_	-15	nA	V _{CB} = -30V	
Collector Catoli Carrent			I _{CBO}			-4	μA	$V_{CB} = -30V, T_{J} = +150^{\circ}C$	
		BC856				-15		V _{CE} = -80V	
Collector Emitter Cutoff Curr	ent	BC857	ICES	_	_	-15	nA	V _{CE} = -50V	
		BC858	<u> </u>			-15		$V_{CE} = -30V$	
Emitter-Base Cutoff Current			I _{EBO}	-	_	-100	nA	$V_{EB} = -5V$	
	BC856A / E	3C857A / BC858A	LDO	_	200				
Small Signal Current Gain		3C857B / BC858B	h _{fe}		330	_	—		
(Note 10)	BC857	7C / BC858C			600				
	BC856A / E	BC857A / BC858A	h _{ie}		2.7				
Input Impedance (Note 10)		3C857B / BC858B			4.5	—	kΩ		
	BC857C / BC858C				8.7			$I_{C} = -2.0 \text{mA}, V_{CE} = -5 \text{V}$	
Output Admittance	BC856A / BC857A / BC858A BC856B / BC857B / BC858B		h _{oe}	—	18		μS	f = 1.0kHz	
(Note 10)					30	- 1			
(7C / BC858C			60			4	
Reverse Voltage Transfer		8C857A / BC858A		_	1.5x10 ⁻⁴				
Ratio (Note 10)		C857B / BC858B	h _{re}		$2x10^{-4}$	_	_		
, ,,		7C / BC858C		405	3x10 ⁻⁴	050			
DC Current Coin (Note 10)		BC857A / BC858A BC857B / BC858B		125	180 290	250		$I_{C} = -2.0 \text{mA}, V_{CE} = -5 \text{V}$	
DC Current Gain (Note 10)		C / BC858C	h _{FE}	220 420	290 520	475 800	_		
	DC031	C / DC030C		420	-75	-300			
Collector-Emitter Saturation	Voltage (Note 10	D)	V _{CE(sat)}	_	-250	-650	mV	$I_{\rm C} = -10$ mA, $I_{\rm B} = -0.5$ mA	
			. ,	000				$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -5.0 {\rm mA}$	
Base-Emitter Turn-On Voltag	ge (Note 10)		V _{BE(on)}	-600	-650	-750	mV	$I_C = -2mA$, $V_{CE} = -5V$	
			52(01)	_	—	-820		$I_{\rm C} = -10 {\rm mA}, V_{\rm CE} = -5 {\rm V}$	
Base-Emitter Saturation Voltage (Note 10)		V _{BE(sat)}	_	-700		mV	$I_{C} = -10 \text{mA}, I_{B} = -0.5 \text{mA}$		
		· ,		-850	-1100		$I_{\rm C} = -100 {\rm mA}, I_{\rm B} = -5 {\rm mA}$		
Output Capacitance			Cobo	—	3	—	pF	$V_{CB} = -10V, f = 1.0MHz$	
Transition Frequency		f⊤	100	200		MHz	$V_{CE} = -5V, I_C = -10mA, f = 100MHz$		
Noise Figure			NF	_	2	10	dB	$\label{eq:VCE} \begin{array}{l} V_{CE} = \text{-}5V, \ I_C = \text{-}200\muA \\ R_S = 2k\Omega, \ f = 1kHz \\ \Deltaf = 200Hz \end{array}$	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

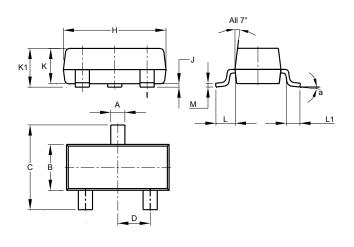






Package Outline Dimensions

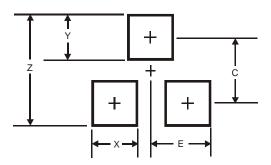
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
К	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	8°								
All	Dimens	ions in	mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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